CMOS SSI

Quad Exclusive "OR" and "NOR" Gates

The MC14070B quad exclusive OR gate and the MC14077B quad exclusive NOR gate are constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. These complementary MOS logic gates find primary use where low power dissipation and/or high noise immunity is desired.

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Double Diode Protection on All Inputs
- MC14070B Replacement for CD4030B and CD4070B Types
- MC14077B Replacement for CD4077B Type

MAXIMUM RATINGS (Voltages Referenced to V_{SS}) (Note 2.)

| Symbol | Parameter | Value | Unit |
|------------------------------------|--|-------------------------------|------|
| V_{DD} | DC Supply Voltage Range | -0.5 to +18.0 | V |
| V _{in} , V _{out} | Input or Output Voltage Range (DC or Transient) | -0.5 to V _{DD} + 0.5 | V |
| I _{in} , I _{out} | Input or Output Current (DC or Transient) per Pin | ±10 | mA |
| P _D | Power Dissipation, per Package (Note 3.) | 500 | mW |
| T _A | Ambient Temperature Range | -55 to +125 | °C |
| T _{stg} | Storage Temperature Range | -65 to +150 | °C |
| TL | Lead Temperature (8–Second Soldering) | 260 | °C |

- Maximum Ratings are those values beyond which damage to the device may occur.
- Temperature Derating: Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



ON Semiconductor

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MARKING DIAGRAMS



PDIP-14 P SUFFIX CASE 646



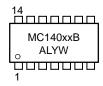


SOIC-14 D SUFFIX CASE 751A





SOEIAJ-14 F SUFFIX CASE 965



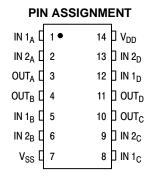
xx = Specific Device Code A = Assembly Location

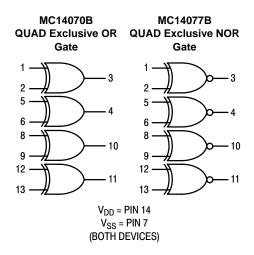
WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|-----------|------------------|
| MC140XXBCP | PDIP-14 | 2000/Box |
| MC140XXBD | SOIC-14 | 2750/Box |
| MC140XXBDR2 | SOIC-14 | 2500/Tape & Reel |
| MC140XXBF | SOEIAJ-14 | See Note 1. |
| MC140XXBFEL | SOEIAJ-14 | See Note 1. |

 For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.





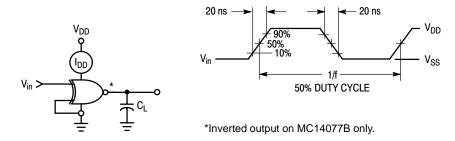
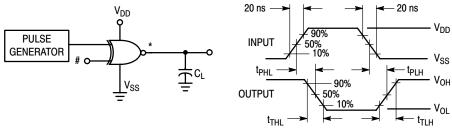


Figure 1. Power Dissipation Test Circuit and Waveform



*Inverted output on MC14077B only. #Connect unused input to V_{DD} for MC14070B, to V_{SS} for MC14077B.

Figure 2. Switching Time Test Circuit and Waveforms

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| | | | V _{DD} | - 5 | 5°C | 25°C | | 125°C | | | |
|--|--------------------|--|------------------------|-----------------------------------|----------------------|-----------------------------------|---|----------------------|-----------------------------------|----------------------|------|
| Characteristic | | Symbol | Vdc | Min | Max | Min | Тур (4.) | Max | Min | Max | Unit |
| Output Voltage V _{in} = V _{DD} or 0 | "0" Level | V _{OL} | 5.0 10 15 | _ _ _ | 0.05 0.05 0.05 | _ _ _ | 0 0 0 | 0.05 0.05 0.05 | _ _ _ | 0.05 0.05 0.05 | Vdc |
| V _{in} = 0 or V _{DD} | "1" Level | V _{OH} | 5.0 10 15 | 4.95 9.95 14.95 | _ _ _ | 4.95 9.95 14.95 | 5.0 10 15 | _ _ _ | 4.95 9.95 14.95 | _ _ _ | Vdc |
| Input Voltage ($V_O = 4.5 \text{ or } 0.5 \text{ Vdc}$) ($V_O = 9.0 \text{ or } 1.0 \text{ Vdc}$) ($V_O = 13.5 \text{ or } 1.5 \text{ Vdc}$) | "0" Level | V _{IL} | 5.0 10 15 | _ _ _ | 1.5 3.0 4.0 | _ _ _ | 2.25 4.50 6.75 | 1.5 3.0 4.0 | _ _ _ | 1.5 3.0 4.0 | Vdc |
| $(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$ | "1" Level | V _{IH} | 5.0 10 15 | 3.5 7.0 11 | _ _ _ | 3.5 7.0 11 | 2.75 5.50 8.25 | _ _ _ | 3.5 7.0 11 | _ _ _ | Vdc |
| Output Drive Current $ (V_{OH} = 2.5 \text{ Vdc}) $ $ (V_{OH} = 4.6 \text{ Vdc}) $ $ (V_{OH} = 9.5 \text{ Vdc}) $ $ (V_{OH} = 13.5 \text{ Vdc}) $ | Source | I _{OH} | 5.0 5.0 10 15 | - 3.0 - 0.64 - 1.6 - 4.2 | | - 2.4 - 0.51 - 1.3 - 3.4 | - 4.2 - 0.88 - 2.25 - 8.8 | _ _ _ _ | - 1.7 - 0.36 - 0.9 - 2.4 | | mAdc |
| $(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$ | Sink | I _{OL} | 5.0 10 15 | 0.64 1.6 4.2 | _ _ _ | 0.51 1.3 3.4 | 0.88 2.25 8.8 | _ _ _ | 0.36 0.9 2.4 | _ _ _ | mAdc |
| Input Current | | I _{in} | 15 | _ | ± 0.1 | _ | ±0.00001 | ± 0.1 | _ | ± 1.0 | μAdc |
| Input Capacitance (V _{in} = 0) | | C _{in} | _ | _ | _ | _ | 5.0 | 7.5 | _ | _ | pF |
| Quiescent Current (Per Package) | | I _{DD} | 5.0 10 15 | _ _ _ | 0.25 0.5 1.0 | _ _ _ | 0.0005 0.0010 0.0015 | 0.25 0.5 1.0 | _ _ _ | 7.5 15 30 | μAdc |
| Total Supply Current (5.) (6.) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching) | | I _T | 5.0 10 15 | | | $I_T = (0$ | 0.3 μΑ/kHz) 0.6 μΑ/kHz) 0.9 μΑ/kHz) | f + I _{DD} | | | μAdc |
| Output Rise and Fall Times $^{(\xi)}$ $(C_L = 50 \text{ pF})$ $t_{TLH}, t_{THL} = (1.35 \text{ ns/pF}) C_L$ $t_{TLH}, t_{THL} = (0.60 \text{ ns/pF}) C_L$ $t_{TLH}, t_{THL} = (0.40 \text{ ns/pF}) C_L$ | + 33 ns + 20 ns | t _{TLH} , t _{THL} | 5.0 10 15 | _ _ _ | _ _ _ | _ _ _ | 100 50 40 | 200 100 80 | _ _ _ | _ _ _ | ns |
| $\begin{array}{c} \text{Propagation Delay Times} \stackrel{(5.)}{\text{CL}} \\ \text{($C_L = 50 \text{ pF}$)} \\ \text{t}_{\text{PLH}}, \text{t}_{\text{PHL}} = (0.90 \text{ ns/pF}) \text{ C}_{\text{L}} \\ \text{t}_{\text{PLH}}, \text{t}_{\text{PHL}} = (0.36 \text{ ns/pF}) \text{ C}_{\text{L}} \\ \text{t}_{\text{PLH}}, \text{t}_{\text{PHL}} = (0.26 \text{ ns/pF}) \text{ C}_{\text{L}} \end{array}$ | + 57 ns | t _{PLH} , t _{PHL} | 5.0 10 15 | _ _ _ | _ _ _ | _ _ _ | 175 75 55 | 350 150 110 | _ _ _ | _ _ _ | ns |

^{4.} Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
5. The formulas given are for the typical characteristics only at 25°C.

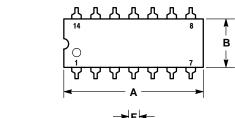
$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

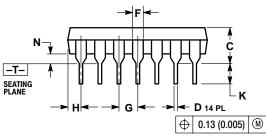
where: I_T is in μH (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and k = 0.002.

^{6.} To calculate total supply current at loads other than 50 pF:

PACKAGE DIMENSIONS

P SUFFIX PLASTIC DIP PACKAGE CASE 646-06 ISSUE M





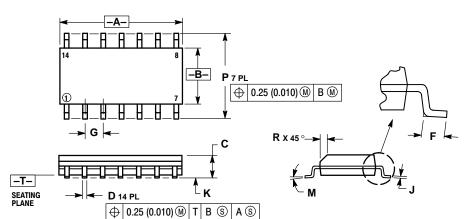


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL

| | INC | HES | MILLIMETERS | | |
|-----|-------|-------|-------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.715 | 0.770 | 18.16 | 18.80 | |
| В | 0.240 | 0.260 | 6.10 | 6.60 | |
| С | 0.145 | 0.185 | 3.69 | 4.69 | |
| D | 0.015 | 0.021 | 0.38 | 0.53 | |
| F | 0.040 | 0.070 | 1.02 | 1.78 | |
| G | 0.100 | BSC | 2.54 BSC | | |
| Н | 0.052 | 0.095 | 1.32 | 2.41 | |
| J | 0.008 | 0.015 | 0.20 | 0.38 | |
| K | 0.115 | 0.135 | 2.92 | 3.43 | |
| L | 0.290 | 0.310 | 7.37 | 7.87 | |
| М | | 10° | | 10° | |
| N | 0.015 | 0.039 | 0.38 | 1.01 | |

PACKAGE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE F

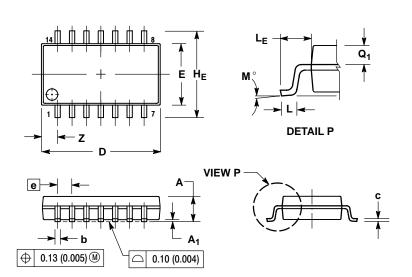


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIN | IETERS | INCHES | | |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 8.55 | 8.75 | 0.337 | 0.344 | |
| В | 3.80 | 4.00 | 0.150 | 0.157 | |
| С | 1.35 | 1.75 | 0.054 | 0.068 | |
| D | 0.35 | 0.49 | 0.014 | 0.019 | |
| F | 0.40 | 1.25 | 0.016 | 0.049 | |
| G | 1.27 | BSC | 0.050 BSC | | |
| J | 0.19 | 0.25 | 0.008 | 0.009 | |
| K | 0.10 | 0.25 | 0.004 | 0.009 | |
| M | 0° | 7° | 0 ° | 7° | |
| P | 5.80 | 6.20 | 0.228 | 0.244 | |
| R | 0.25 | 0.50 | 0.010 | 0.019 | |

PACKAGE DIMENSIONS

F SUFFIX PLASTIC EIAJ SOIC PACKAGE CASE 965-01 **ISSUE O**



NOTES:

- DTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| | MILLIN | IETERS | INCHES | | |
|----------------|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | | 2.05 | | 0.081 | |
| A ₁ | 0.05 | 0.20 | 0.002 | 0.008 | |
| b | 0.35 | 0.50 | 0.014 | 0.020 | |
| c | 0.18 | 0.27 | 0.007 | 0.011 | |
| D | 9.90 | 10.50 | 0.390 | 0.413 | |
| Е | 5.10 | 5.45 | 0.201 | 0.215 | |
| е | 1.27 | BSC | 0.050 BSC | | |
| HE | 7.40 | 8.20 | 0.291 | 0.323 | |
| 0.50 | 0.50 | 0.85 | 0.020 | 0.033 | |
| LE | 1.10 | 1.50 | 0.043 | 0.059 | |
| M | 0 ° | 10 ° | 0 ° | 10 ° | |
| Q1 | 0.70 | 0.90 | 0.028 | 0.035 | |
| Z | | 1.42 | | 0.056 | |



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